

# Influence of Temperature on Exciton Dynamic Processes in a CuPc/C60 Based Solar Cell

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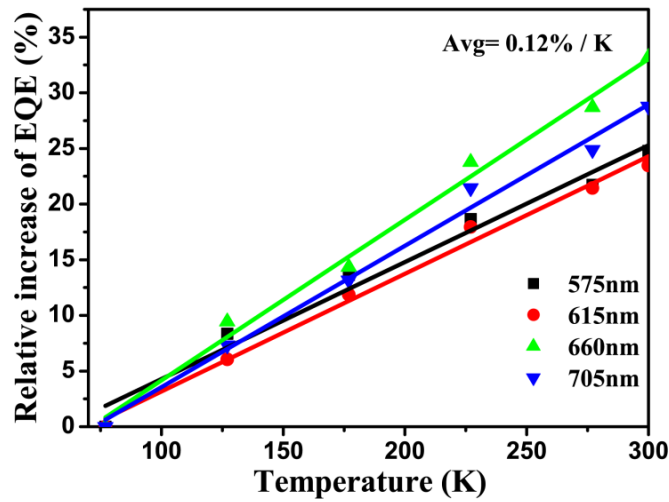
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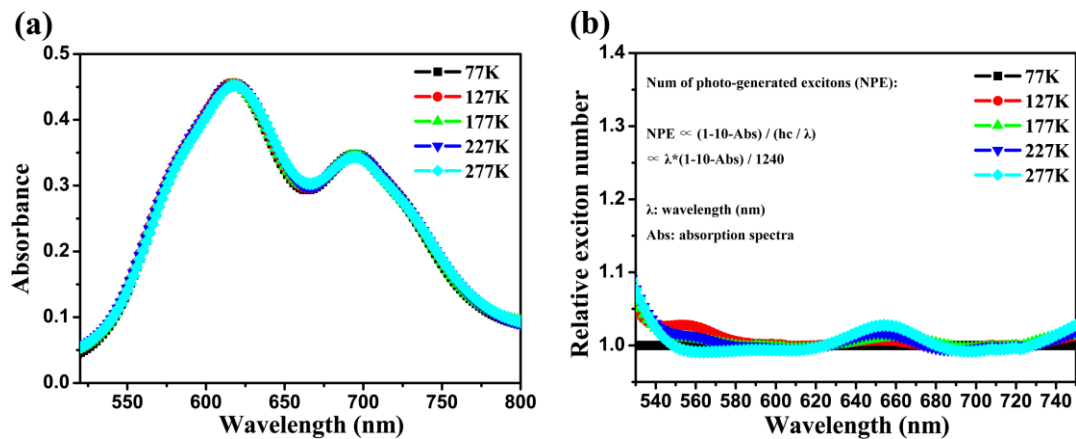
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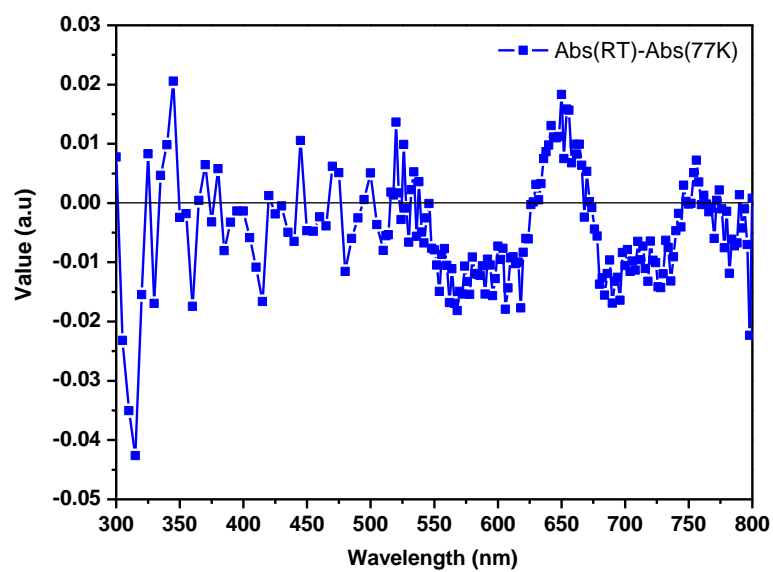
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**Figure S1.** The relative increase of EQE with temperature at different wavelengths



**Figure S2.** (a) Absorption spectra for a 50 nm CuPc thin film thermal evaporated on quartz substrate and (b) the relative changes of absorption efficiency.



**Figure S3.** Absorption ratio with 77 K and 300 K.